



mm inch

High sensitivity and low on-resistance. DIP (2 Form B) 8-pin type.

HE PhotoMOS (AQW454)

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FEATURES

1. Compact 8-pin DIP size

The device comes in a compact (W) $6.4\times(L) 9.78\times(H) 3.9 \text{ mm}$ (W) $.252\times(L)$ $.385\times(H) .154 \text{ inch}$, 8-pin DIP size (through hole terminal type).

2. Applicable for 2 Form B use as well as two independent 1 Form B use.

3. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. High sensitivity, low ON resistance Can control a maximum 0.16 A (AQW454) load current with a 5 mA input current. Low ON resistance of 16 Ω (AQW454). Stable operation because there are no metallic contact parts.

5. Low-level off state leakage current

The SSR has an off state leakage current of several miliamperes, whereas the PhotoMOS relay has typ. 100 pA even with the rated load voltage of 400 V (AQW454).

6. Low thermal electromotive force (Approx. 1 $\mu\text{V})$

TYPICAL APPLICATIONS

- Security equipment
- High-speed inspection machine
- Measuring equipment
- Telecommunication equipment
- Sensors

TYPES

Туре	Output rating*			I	Packing quantity			
			Through hole terminal	ough hole Surface-mount terminal				
	Load voltage	Load current	Tube packing style		Tape and reel packing style			
					Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	Tube	Tape and reel
AC/DC	400 V	120 mA	AQW454	AQW454A	AQW454AX	AQW454AZ	1 tube contains 40 pcs. 1 batch contains 400 pcs.	1,000 pcs

*Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

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Item		Symbol	AQW454(A)	Remarks	
	LED forward current	lF	50 mA		
la nut	LED reverse voltage	Vr	5 V		
Input	Peak forward current	IFP	1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin	75 mW		
	Load voltage (peak AC)	VL	400 V		
Output	Continuous load current	IL.	0.12 A (0.16 A)	A connection: Peak AC, DC (): for one 1b-circuit	
	Peak load current	Ipeak	0.36 A	A connection: 100 ms (1 shot), V _L = DC	
	Power dissipation	Pout	800 mW		
Total power dissipation		Ρτ	850 mW		
I/O isolation voltage		Viso	1,500 V AC	Between input and output/between contact sets	
Terrer enertime lineite	Operating	Topr	−40°C to +85°C −40°F to +185°F	Non-condensing at low temperatures	
remperature limits	Storage	Tstg	-40°C to +100°C -40°F to +212°F		

HE PhotoMOS (AQW454)

Item				Symbol	AQW454(A)	Condition	
Input			Typical	I	0.9 mA	h – Mox	
		e (OFF) current	Maximum	IFoff	3 mA	IL = IVIAX.	
			Minimum	Fon	0.4 mA	I∟ = Max.	
	LED reverse	(ON) current	Typical		0.8 mA		
	LED dropout voltage		Typical	VF	1.25 V (1.14 V at I⊧ = 5 mA)	I⊧ = 50 mA	
			Maximum		1.5 V		
Output	On resistance		Typical	Ron	11 Ω	$I_F = 0 mA$ $I_L = Max.$ Within 1 s on time	
			Maximum		16 Ω		
	Off state lea	kage current	Maximum	Leak	1 μΑ	l⊧ = 5 mA V∟ = Max.	
	Switching speed	Operate (OFF) time*	Typical	Toff	1.2 ms	I⊧ = 0 mA → 5 mA	
			Maximum		2 ms	I∟ = Max.	
		Reverse (ON) time*	Typical	-	0.36 ms	I⊧ = 5 mA → 0 mA	
Transfer char- acteristics			Maximum	Ion	1 ms	I∟ = Max.	
			Typical	C	0.8 pF	f = 1 MHz	
	1/O capacita	nce	Maximum	Ciso	1.5 pF	$V_B = 0 V$	
	Initial I/O isc	lation resistance	Minimum	Riso	1,000 MΩ	500 V DC	
Note: Recomme	ndable LED fo	rward current I _F = 5	mA.			Type of connection	

Note: Recommendable LED forward current IF = 5 mA.

*Operate/Reverse time



Dimensions Schematic and Wiring Diagrams

Cautions for Use

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 0 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)





temperature characteristics

Continuous load current: 120 mA (DC)

Load voltage: 400 V (DC);

Am

reverse (ON) current,

Ē

0

40 -20 0 20 40 60

4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: 400 V (DC);

Continuous load current: 120 mA (DC)



8. Current vs. voltage characteristics of output at MOS portion Measured portion: between terminals 5 and 6,





9. Off state leakage current vs. load voltage characteristics

Ambient temperature, °C

8085

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz;





11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F

